NSN 5962-00-511-3888

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.740 inches and 0.890 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

Between 0.140 inches and 0.205 inches

Maximum Power Dissipation Rating:

625.0 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-55.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and positive outputs and bipolar and w/enable and w/buffered output and w/decoded output and

w/disable and programmed and programmable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

80.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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